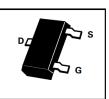


BSS84

### SOT23 P-CHANNEL ENHANCEMENT MODE VERTICAL DMOS FET

### PARTMARKING DETAIL — SP



## ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	VALUE	UNIT
Drain-Source Voltage	V <sub>DS</sub>	-50	V
Continuous Drain Current	I <sub>D</sub>	-130	mA
Pulsed Drain Current	I <sub>DM</sub>	-520	mA
Gate-Source Voltage Peak	V <sub>GS</sub>	±20	V
Power Dissipation at T <sub>amb</sub> =25°C	P <sub>TOT</sub>	360	mW
Operating and Storage Temperature Range	t <sub>j</sub> :t <sub>stg</sub>	-55 to +150	°C

# ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}C$ ).

	1					
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS.
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-50			V	V <sub>GS</sub> =0V, I <sub>D</sub> =0.25mA
Gate-Source Threashold Voltage	V <sub>GS(th)</sub>	-0.8	-1.5	-2.0	V	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-1mA
Zero gate Voltage Drain Current	I <sub>DSS</sub>		-1 -2	- 15 -60	μΑ μΑ	$T_{j}=25 \ ^{\circ}C$ $T_{j}=125 \ ^{\circ}C$ $V_{DS}=-50V, V_{GS}=0V(2)$ $T_{i}=25 \ ^{\circ}C$
				-100		$V_{DS} = -25V, V_{GS} = 0V$
Gate-Source Leakage Current	I <sub>GSS</sub>		-1	-10	nA	$V_{GS} = \pm 20V$ $V_{DS} = 0V$
Drain Source On-State Resistance (1)	R <sub>DS(on)</sub>		6	10	Ω	V <sub>GS</sub> =-5V I <sub>D</sub> =-100mA
Forward Transconductance (1) (2)	9 <sub>fs</sub>	0.05	0.07		S	V <sub>DS</sub> =-25V I <sub>D</sub> =-100mA
Input Capacitance (2)	Ciss		40			V <sub>GS</sub> =0V V <sub>DS</sub> =-25V f=1MHz
Output Capacitance	Coss		15		pF	
Reverse Transfer Capacitance (2)	C <sub>rss</sub>		6		<b>P</b> .	
Turn-On Time t <sub>on</sub> Turn-Off Time t <sub>off</sub>	td(on)		10		ns	$V_{DD}$ =-30V $I_{D}$ =-0.27A $V_{GS}$ =-10V $R_{GS}$ =50 $\Omega$
	t <sub>r</sub>		10			
	t <sub>d(off)</sub>		18			
	t <sub>f</sub>		25			

\* (1) Measured under pulsed conditions. Pulse width =  $300\mu$ s. Duty cycle 2% (2) Sample test.



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